



FEATURES

- 16-bit resolution with no missing codes
- Throughput: 500 kSPS
- INL: +/-0.25 LSB typical, ±0.65 LSB max (±10 ppm of FSR)
- Dynamic range: 96.5 dB typical @ 500 kSPS
- SINAD: 96 dB typical @ 1 kHz, REF = 5V
- THD: -120 dB typical @ 1 kHz, REF = 5V
- True differential analog input range: ±VREF
 - 0 V to V_{REF} with V_{REF} up to V_{DD} on both inputs
- No pipeline delay
- Single-supply 5 V operation with
 - 1.8 V/2.5 V/3 V/5 V logic interface
- Serial interface SPI®/QSPI™/MICROWIRE™/DSP-compatible
- Daisy-chain multiple ADCs and busy indicator
- Power dissipation
 - 4 mW @ 5 V/100 kSPS
 - 40 µW @ 5 V/1 kSPS
- Standby current: 1 nA
- 10-lead package: MSOP (MSOP-8 size) and
 - 3 mm × 3 mm QFN¹ (LFCSP) (SOT-23 size)
- Pin-for-pin compatible with the [AD7687](#), [AD7688](#) and **18-bit AD7690 and AD7691**

APPLICATIONS

- Battery-powered equipment
- Data acquisitions
- Seismic data acquisition systems
- DVMs
- Instrumentation
- Medical instruments

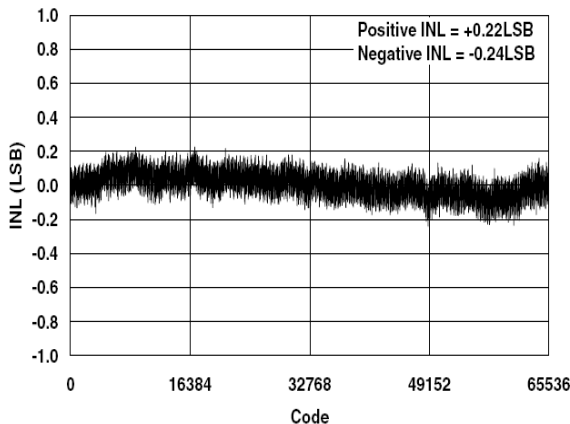


Figure 1. Integral Nonlinearity vs. Code

APPLICATION DIAGRAM

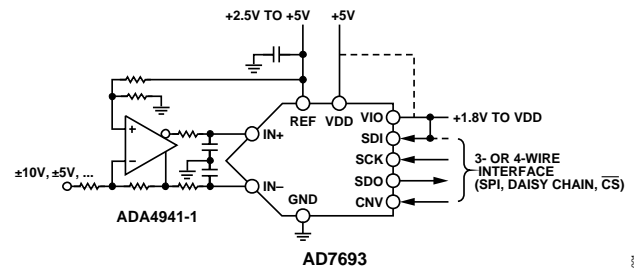


Figure 2.

Table 1. MSOP, QFN¹ (LFCSP)/SOT-23
14-/16-/18-Bit PuLSAR ADC

Type	100 kSPS	250 kSPS	400 kSPS to 500 kSPS	ADC Driver
18-Bit		AD7691	AD7690	ADA4941-1 ADA4841-x
16-Bit True Differential	AD7684	AD7687	AD7688 AD7693	ADA4941-1 ADA4841-x
16-Bit Pseudo Differential/Unipolar	AD7683 AD7680	AD7685 AD7694	AD7686	ADA4841-x
14-Bit	AD7940	AD7942	AD7946	ADA4841-x

¹ QFN package in development. Contact sales for samples and availability.

GENERAL DESCRIPTION

The AD7693 is a 16-bit, successive approximation, analog-to-digital converter (ADC) that operates from a single power supply, VDD. It contains a low power, high speed, 16-bit sampling ADC with no missing codes, an internal conversion clock, and a versatile serial interface port. On the CNV rising edge, it samples the voltage difference between the IN+ and IN- pins. The voltages on these pins swing in opposite phase between 0 V and REF. The reference voltage, REF, is applied externally and can be set up to the supply voltage, VDD.

Its power scales linearly with throughput.

The SPI-compatible serial interface also features the ability, using the SDI input, to daisy-chain several ADCs on a single, 3-wire bus and provides an optional busy indicator. It is compatible with 1.8 V, 2.5 V, 3 V, or 5 V logic, using the separate VIO supply.

The AD7693 is housed in a 10-lead MSOP or a 10-lead QFN¹ (LFCSP) with operation specified from -40°C to +85°C.

¹ QFN package in development. Contact sales for samples and availability.

Rev. PrB

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REVISION HISTORY

SPECIFICATIONS

VDD = 4.5 V to 5.5 V, VIO = 2.3 V to VDD, VREF = VDD, all specifications T_{MIN} to T_{MAX}, unless otherwise noted.

Table 2.

Parameter	Conditions/Comments	Min	Typ	Max	Unit
RESOLUTION		18			Bits
ANALOG INPUT					
Voltage Range	IN+ – (IN–)	–V _{REF}		+V _{REF}	V
Absolute Input Voltage	IN+, IN–	–0.1		V _{REF} + 0.1	V
Common-Mode Input Range	IN+, IN–	0	V _{REF} /2	V _{REF} /2 + 0.1	V
Analog Input CMRR	f _{IN} = 250 kHz		65		dB
Leakage Current at 25°C	Acquisition phase		1		nA
Input Impedance ¹					
THROUGHPUT					
Conversion Rate		0		500	kSPS
Transient Response	Full-scale step			400	ns
ACCURACY					
No Missing Codes		16			Bits
Integral Linearity Error		–0.65	±0.25	+0.65	LSB
Differential Linearity Error		–0.5	±0.2	+0.5	LSB ²
Transition Noise	REF = VDD = 5 V		0.16		LSB
Gain Error ³		–30	±1.5	+30	LSB
Gain Error Temperature Drift			±0.5		ppm/°C
Zero Error ³		–10		+10	LSB
Zero Temperature Drift			±1		ppm/°C
Power Supply Sensitivity	VDD = 5 V ± 5%		±1		ppm
AC ACCURACY					
Dynamic Range	V _{REF} = 5 V	96	96.5		dB ⁴
Signal-to-Noise	f _{IN} = 1 kHz, V _{REF} = 5 V	95.5	96		dB
	f _{IN} = 1 kHz, V _{REF} = 2.5 V		93		dB
Spurious-Free Dynamic Range	f _{IN} = 1 kHz, V _{REF} = 5 V		–120		dB
Total Harmonic Distortion	f _{IN} = 1 kHz, V _{REF} = 5 V		–120		dB
Signal-to-(Noise + Distortion)	f _{IN} = 1 kHz, V _{REF} = 5 V	95.5	96		dB
Intermodulation Distortion ⁵			TBD		dB

¹ See the Analog Inputs section.

² LSB means least significant bit. With the ±5 V input range, one LSB is 152.6 μV.

³ See the Terminology section. These specifications include full temperature range variation but not the error contribution from the external reference.

⁴ All specifications in dB are referred to a full-scale input FSR. Tested with an input signal at 0.5 dB below full scale, unless otherwise specified.

⁵ f_{IN1} = 21.4 kHz and f_{IN2} = 18.9 kHz, with each tone at –7 dB below full scale.

VDD = 4.5 V to 5.5 V, VIO = 2.3 V to VDD, VREF = VDD, all specifications T_{MIN} to T_{MAX}, unless otherwise noted.

Table 3.

Parameter	Conditions/Comments	Min	Typ	Max	Unit
REFERENCE					
Voltage Range		0.5		VDD + 0.3	V
Load Current	500 kSPS, REF = 5 V		100		μA
SAMPLING DYNAMICS					
–3 dB Input Bandwidth			9		MHz
Aperture Delay	VDD = 5V		2.5		ns
DIGITAL INPUTS					
Logic Levels					
V _{IL}		–0.3		+0.3 × VIO	V
V _{IH}		0.7 × VIO		VIO + 0.3	V
I _{IL}		–1		+1	μA
I _{IH}		–1		+1	μA
DIGITAL OUTPUTS					
Data Format	Serial 16 bits twos complement				
Pipeline Delay ¹					
V _{OL}	I _{SINK} = +500 μA			0.4	V
V _{OH}	I _{SOURCE} = –500 μA	VIO – 0.3			V
POWER SUPPLIES					
VDD	Specified performance	4.5		5.5	V
VIO	Specified performance	2.3		VDD + 0.3	V
VIO Range		1.8		VDD + 0.3	V
Standby Current ^{2, 3}	VDD and VIO = 5 V, 25°C		1	50	nA
Power Dissipation	100 SPS throughput		5		μW
	100 kSPS throughput		5		mW
	500 kSPS throughput		15		mW
Energy per Conversion			50		nJ/sample
TEMPERATURE RANGE ⁴					
Specified Performance	T _{MIN} to T _{MAX}	–40		+85	°C

¹ Conversion results available immediately after completed conversion.

² With all digital inputs forced to VIO or GND as required.

³ During acquisition phase.

⁴ Contact an Analog Devices sales representative for extended temperature range.

TIMING SPECIFICATIONS

VDD = 4.5 V to 5.5 V, VIO = 2.3 V to VDD, V_{REF} = VDD, all specifications T_{MIN} to T_{MAX}, unless otherwise noted.

Table 4. ¹

Parameter	Symbol	Min	Typ	Max	Unit
Conversion Time: CNV Rising Edge to Data Available	t _{CONV}	0.5		1.6	μs
Acquisition Time	t _{ACQ}	400			ns
Time Between Conversions	t _{CVC}	2.0			μs
CNV Pulse Width ($\overline{\text{CS}}$ Mode)	t _{CNVH}	10			ns
SCK Period ($\overline{\text{CS}}$ Mode)	t _{SCK}	15			ns
SCK Period (Chain Mode)	t _{SCK}				
VIO Above 4.5 V		17			ns
VIO Above 3 V		18			ns
VIO Above 2.7 V		19			ns
VIO Above 2.3 V		20			ns
SCK Low Time	t _{SCKL}	7			ns
SCK High Time	t _{SCKH}	7			ns
SCK Falling Edge to Data Remains Valid	t _{HSDO}	4			ns
SCK Falling Edge to Data Valid Delay	t _{DSDO}				
VIO Above 4.5 V				14	ns
VIO Above 3 V				15	ns
VIO Above 2.7 V				16	ns
VIO Above 2.3 V				17	ns
CNV or SDI Low to SDO D15 MSB Valid ($\overline{\text{CS}}$ Mode)	t _{EN}				
VIO Above 4.5 V				15	ns
VIO Above 2.7 V				18	ns
VIO Above 2.3 V				22	ns
CNV or SDI High or Last SCK Falling Edge to SDO High Impedance ($\overline{\text{CS}}$ Mode)	t _{DIS}			25	ns
SDI Valid Setup Time from CNV Rising Edge ($\overline{\text{CS}}$ Mode)	t _{SSDICNV}	15			ns
SDI Valid Hold Time from CNV Rising Edge ($\overline{\text{CS}}$ Mode)	t _{HSDICNV}	0			ns
SCK Valid Setup Time from CNV Rising Edge (Chain Mode)	t _{SSCKCNV}	5			ns
SCK Valid Hold Time from CNV Rising Edge (Chain Mode)	t _{HSCKCNV}	10			ns
SDI Valid Setup Time from SCK Falling Edge (Chain Mode)	t _{SSDISCK}	3			ns
SDI Valid Hold Time from SCK Falling Edge (Chain Mode)	t _{HSDISCK}	4			ns
SDI High to SDO High (Chain Mode with BUSY Indicator)	t _{DSDOSDI}				
VIO Above 4.5 V				15	ns
VIO Above 2.3 V				26	ns

¹ See Figure 3 and Figure 4 for load conditions.

ABSOLUTE MAXIMUM RATINGS

Table 5.

Parameter	Rating
Analog Inputs IN+, ¹ IN ⁻¹	GND – 0.3 V to VDD + 0.3 V or ±130 mA
REF	GND – 0.3 V to VDD + 0.3 V
Supply Voltages	
VDD, VIO to GND	–0.3 V to +7 V
VDD to VIO	±7 V
Digital Inputs to GND	–0.3 V to VIO + 0.3 V
Digital Outputs to GND	–0.3 V to VIO + 0.3 V
Storage Temperature Range	–65°C to +150°C
Junction Temperature	150°C
θ _{JA} Thermal Impedance (MSOP-10)	200°C/W
θ _{JC} Thermal Impedance (MSOP-10)	44°C/W
Lead Temperature Range	JEDEC J-STD-20

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

¹ See the Analog Inputs section.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

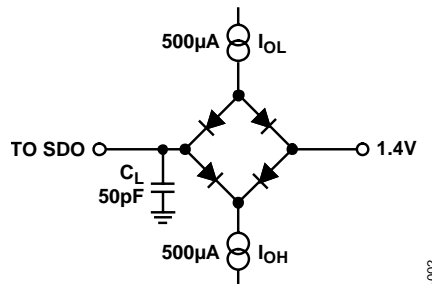
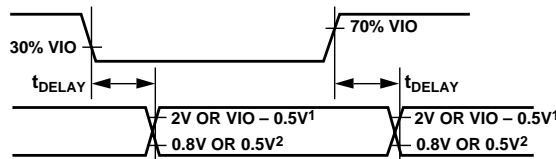


Figure 3. Load Circuit for Digital Interface Timing



¹2V IF VIO ABOVE 2.5V, VIO – 0.5V IF VIO BELOW 2.5V.
²0.8V IF VIO ABOVE 2.5V, 0.5V IF VIO BELOW 2.5V.

Figure 4. Voltage Levels for Timing

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

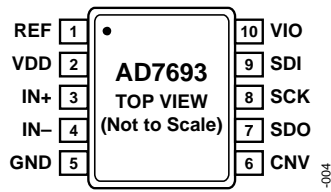
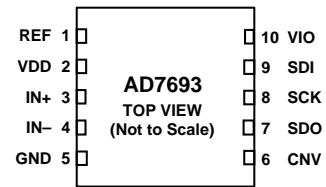


Figure 5. 10-Lead MSOP Pin Configuration



NOTES
1. QFN PACKAGE IN DEVELOPMENT. CONTACT SALES FOR SAMPLES AND AVAILABILITY.

Figure 6. 10-Lead QFN (LFCSP) Pin Configuration

Table 6. Pin Function Descriptions

Pin No.	Mnemonic	Type ¹	Description
1	REF	AI	Reference Input Voltage. The REF range is from 0.5 V to VDD. It is referred to the GND pin. This pin should be decoupled closely to the pin with a 10 μ F capacitor.
2	VDD	P	Power Supply.
3	IN+	AI	Differential Positive Analog Input.
4	IN-	AI	Differential Negative Analog Input.
5	GND	P	Power Supply Ground.
6	CNV	DI	Convert Input. This input has multiple functions. On its leading edge, it initiates the conversions and selects the interface mode of the part; chain or \overline{CS} mode. In chain mode, the data should be read when CNV is high. In \overline{CS} mode, it enables the SDO pin when low.
7	SDO	DO	Serial Data Output. The conversion result is output on this pin. It is synchronized to SCK.
8	SCK	DI	Serial Data Clock Input. When the part is selected, the conversion result is shifted out by this clock.
9	SDI	DI	Serial Data Input. This input provides multiple features. It selects the interface mode of the ADC as follows: Chain mode is selected if SDI is low during the CNV rising edge. In this mode, SDI is used as a data input to daisy-chain the conversion results of two or more ADCs onto a single SDO line. The digital data level on SDI is output on SDO with a delay of 16 SCK cycles. \overline{CS} mode is selected if SDI is high during the CNV rising edge. In this mode, either SDI or CNV can enable the serial output signals when low, and if SDI or CNV is low when the conversion is complete, the BUSY indicator feature is enabled.
10	VIO	P	Input/Output Interface Digital Power. Nominally at the same supply as the host interface (1.8 V, 2.5 V, 3 V, or 5 V).

¹AI = analog input, DI = digital input, DO = digital output, and P = power.

TERMINOLOGY

Least Significant Bit (LSB)

The least significant bit, or LSB, is the smallest increment that can be represented by a converter. For an analog-to-digital converter with N bits of resolution, the LSB expressed in volts is

$$LSB(V) = \frac{V_{INP-P}}{2^N}$$

Integral Nonlinearity Error (INL)

INL refers to the deviation of each individual code from a line drawn from negative full scale through positive full scale. The point used as negative full scale occurs $\frac{1}{2}$ LSB before the first code transition. Positive full scale is defined as a level $1\frac{1}{2}$ LSB beyond the last code transition. The deviation is measured from the middle of each code to the true straight line (see Figure 25).

Differential Nonlinearity Error (DNL)

In an ideal ADC, code transitions are 1 LSB apart. DNL is the maximum deviation from this ideal value. It is often specified in terms of resolution for which no missing codes are guaranteed.

Zero Error

Zero error is the difference between the ideal midscale voltage, that is, 0 V, from the actual voltage producing the midscale output code, that is, 0 LSB.

Gain Error

The first transition (from 100 . . . 00 to 100 . . . 01) should occur at a level $\frac{1}{2}$ LSB above nominal negative full scale (-4.999847 V for the ± 5 V range). The last transition (from 011 . . . 10 to 011 . . . 11) should occur for an analog voltage $1\frac{1}{2}$ LSB below the nominal full scale ($+4.999771$ V for the ± 5 V range.) The gain error is the deviation of the difference between the actual level of the last transition and the actual level of the first transition from the difference between the ideal levels.

Spurious-Free Dynamic Range (SFDR)

SFDR is the difference, in decibels, between the rms amplitude of the input signal and the peak spurious signal.

Effective Number of Bits (ENOB)

ENOB is a measurement of the resolution with a sine wave input. It is related to SINAD by the following formula:

$$ENOB = (SINAD_{dB} - 1.76)/6.02$$

and is expressed in bits.

Total Harmonic Distortion (THD)

THD is the ratio of the rms sum of the first five harmonic components to the rms value of a full-scale input signal and is expressed in dB.

Dynamic Range

Dynamic range is the ratio of the rms value of the full scale to the total rms noise measured with the inputs shorted together. The value for dynamic range is expressed in decibels.

Signal-to-Noise Ratio (SNR)

SNR is the ratio of the rms value of the actual input signal to the rms sum of all other spectral components below the Nyquist frequency, excluding harmonics and dc. The value for SNR is expressed in decibels.

Signal-to-(Noise + Distortion) Ratio (SINAD)

SINAD is the ratio of the rms value of the actual input signal to the rms sum of all other spectral components below the Nyquist frequency, including harmonics but excluding dc. The value for SINAD is expressed in decibels.

Aperture Delay

Aperture delay is the measure of the acquisition performance. It is the time between the rising edge of the CNV input and when the input signal is held for a conversion.

Transient Response

Transient response is the time required for the ADC to accurately acquire its input after a full-scale step function is applied.

TYPICAL PERFORMANCE CHARACTERISTICS

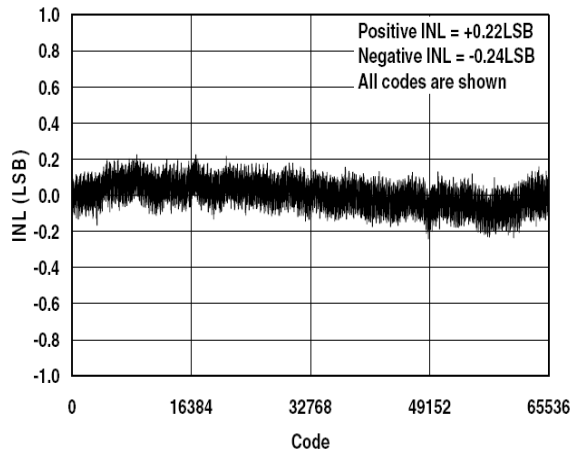


Figure 7. Integral Nonlinearity vs. Code

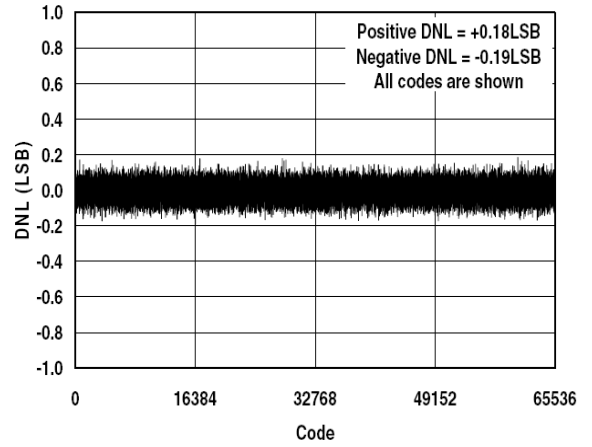


Figure 10. Differential Nonlinearity vs. Code

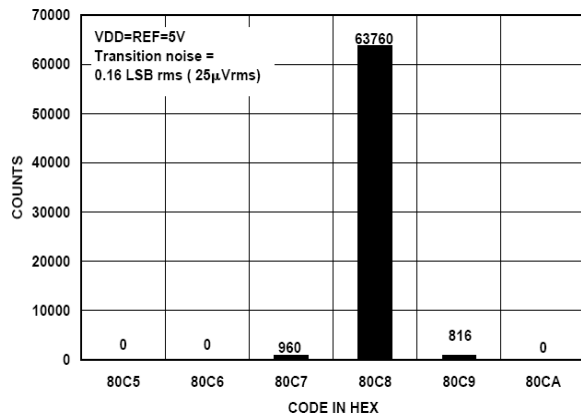


Figure 8. Histogram of a DC Input at the Code Center

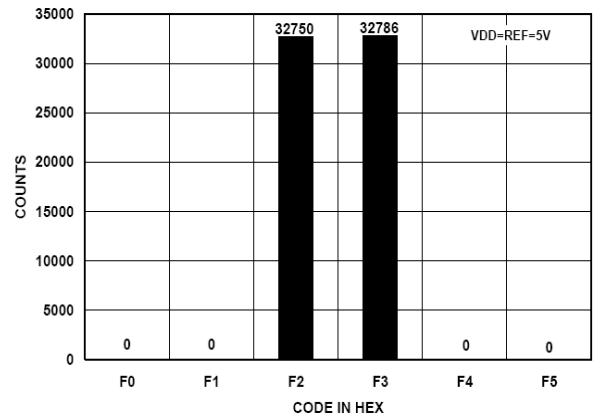


Figure 11. Histogram of a DC Input at the Code Transition

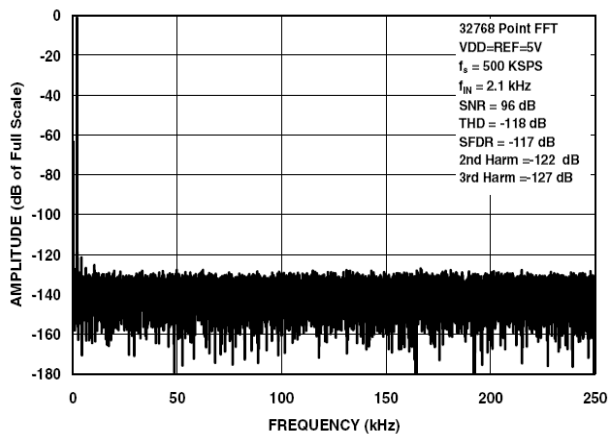


Figure 9. FFT Plot

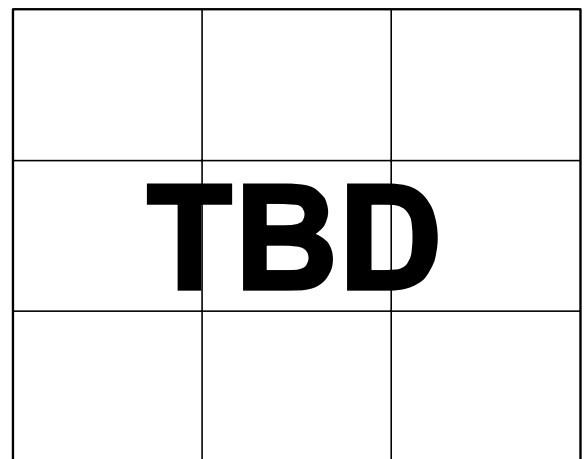


Figure 12. SNR vs. Input Level

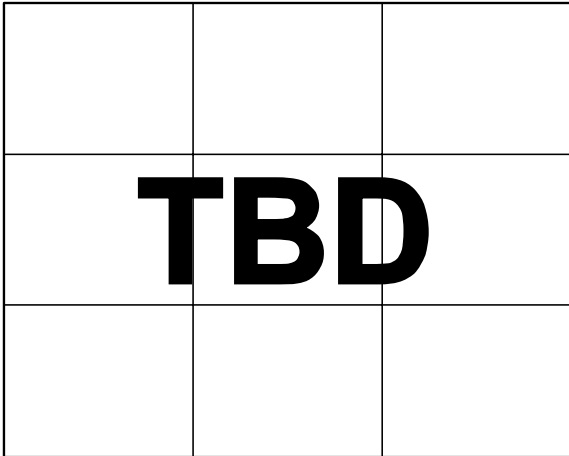


Figure 13. SNR, SINAD, and ENOB vs. Reference Voltage

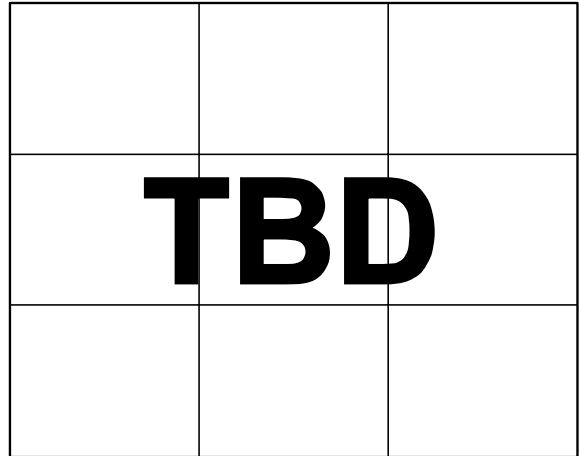


Figure 16. THD, SFDR vs. Reference Voltage

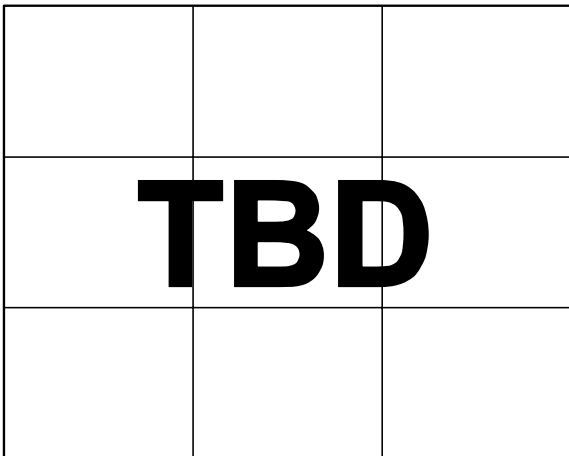


Figure 14. SNR vs. Temperature

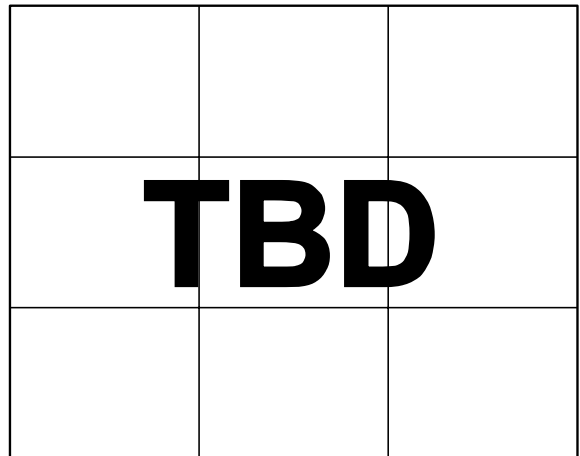


Figure 17. THD vs. Temperature

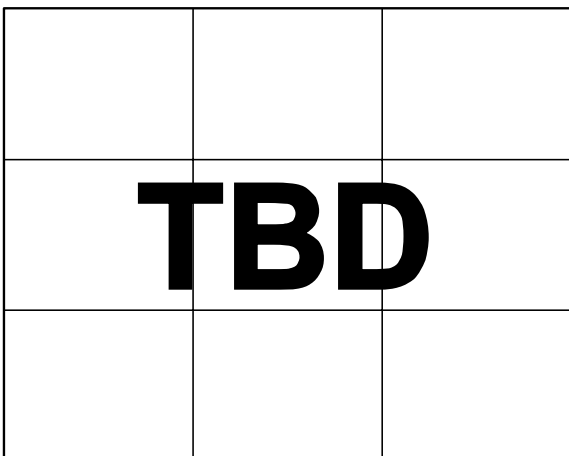


Figure 15. SINAD vs. Frequency

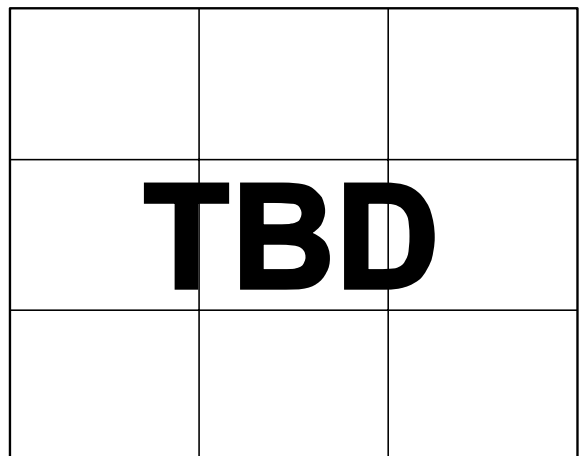


Figure 18. THD vs. Frequency

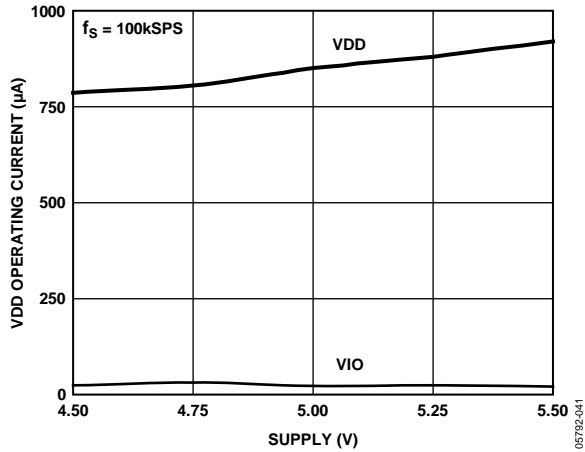


Figure 19. Operating Currents vs. Supply

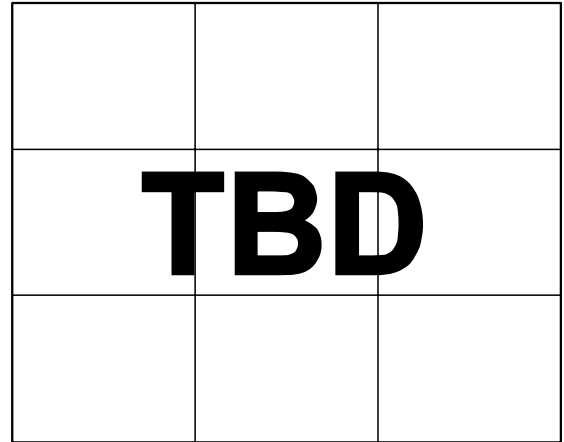


Figure 22. Offset and Gain Error vs. Temperature

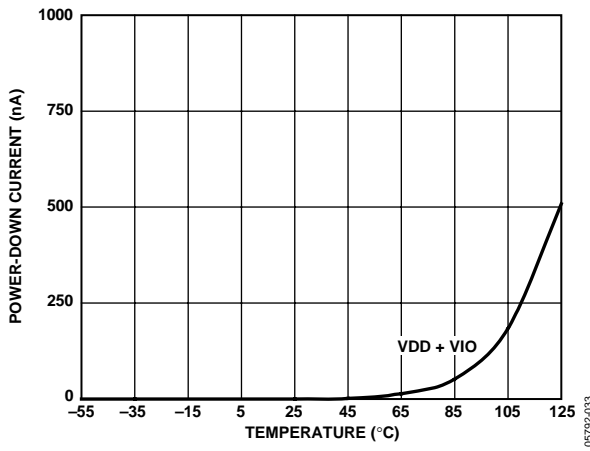


Figure 20. Power-Down Currents vs. Temperature

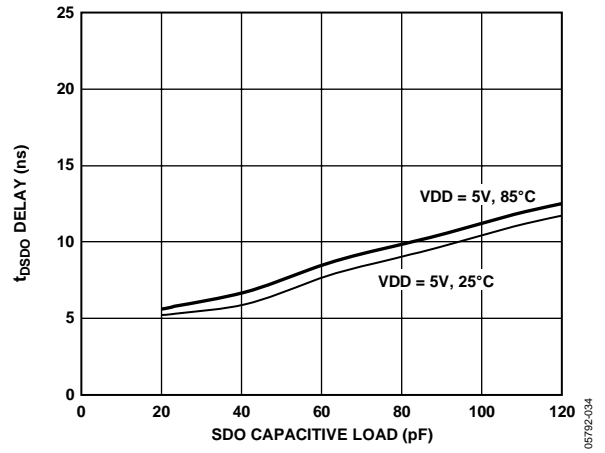


Figure 23. t_{SDO} Delay vs. Capacitance Load and Supply

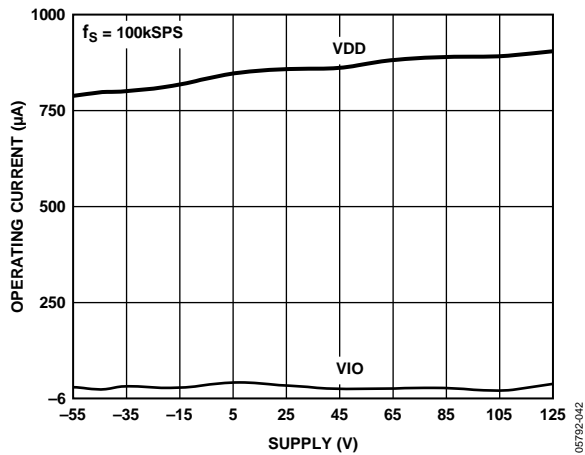


Figure 21. Operating Currents vs. Temperature

THEORY OF OPERATION

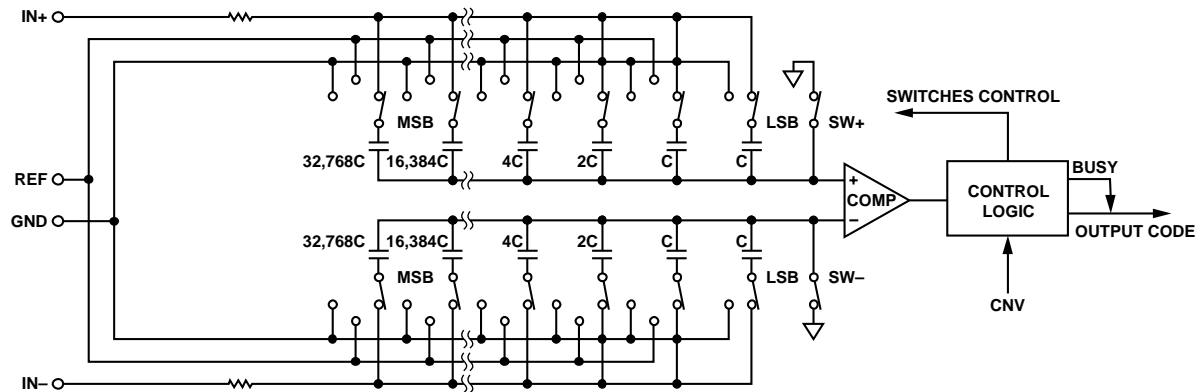


Figure 24. ADC Simplified Schematic

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CIRCUIT INFORMATION

The AD7693 is a fast, low power, single-supply, precise, 16-bit ADC using a successive approximation architecture.

The AD7693 is capable of converting 500,000 samples per second (500 kSPS) and powers down between conversions. When operating at 1 kSPS, for example, it consumes 40 μ W typically, ideal for battery-powered applications.

The AD7693 provides the user with an on-chip track-and-hold and does not exhibit pipeline delay or latency, making it ideal for multiple multiplexed channel applications.

The AD7693 is specified from 4.5 V to 5.5 V and can be interfaced to any 1.8 V to 5 V digital logic family. It is housed in a 10-lead MSOP or a tiny 10-lead QFN (LFCSP) that combines space savings and allows flexible configurations.

It is pin-for-pin compatible with the 16-bit [AD7687](#) and [AD7688](#) and with the 18-bit [AD7690](#) and [AD7691](#).

CONVERTER OPERATION

The AD7693 is a successive approximation ADC based on a charge redistribution DAC. Figure 24 shows the simplified schematic of the ADC. The capacitive DAC consists of two identical arrays of 16 binary-weighted capacitors, which are connected to the two comparator inputs.

During the acquisition phase, terminals of the array tied to the comparator's input are connected to GND via SW+ and SW-. All independent switches are connected to the analog inputs.

Thus, the capacitor arrays are used as sampling capacitors and acquire the analog signal on the IN+ and IN- inputs. When the acquisition phase is complete and the CNV input goes high, a conversion phase is initiated. When the conversion phase begins, SW+ and SW- are opened first. The two capacitor arrays are then disconnected from the inputs and connected to the GND input. Therefore, the differential voltage between the inputs IN+ and IN- captured at the end of the acquisition phase is applied to the comparator inputs, causing the comparator to become unbalanced. By switching each element of the capacitor array between GND and REF, the comparator input varies by binary-weighted voltage steps ($V_{REF}/2$, $V_{REF}/4$... $V_{REF}/32,768$). The control logic toggles these switches, starting with the MSB, to bring the comparator back into a balanced condition. After the completion of this process, the part returns to the acquisition phase, and the control logic generates the ADC output code and a busy signal indicator.

Because the AD7693 has an on-board conversion clock, the serial clock, SCK, is not required for the conversion process.

Transfer Functions

The ideal transfer characteristic for the AD7693 is shown in Figure 25 and Table 7.

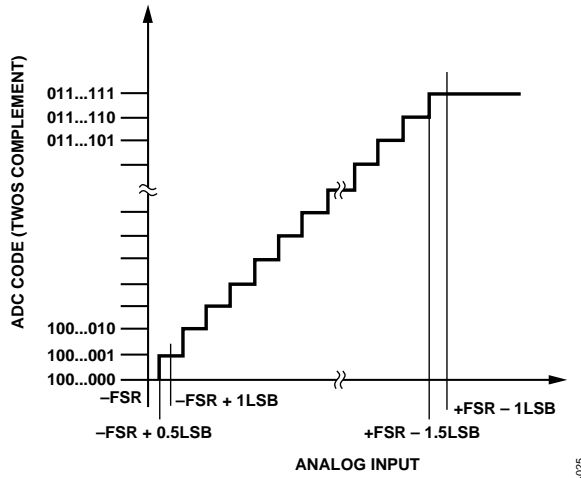


Figure 25. ADC Ideal Transfer Function

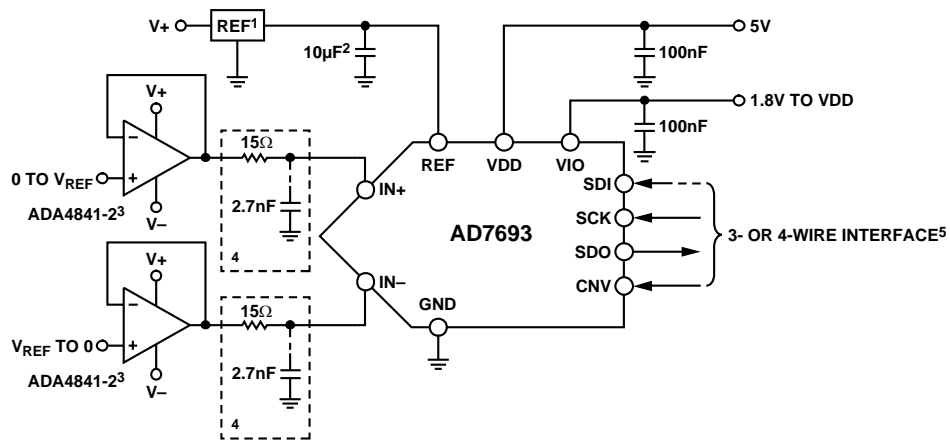
TYPICAL CONNECTION DIAGRAM

Figure 26 shows an example of the recommended connection diagram for the AD7693 when multiple supplies are available.

Table 7. Output Codes and Ideal Input Voltages

Description	Analog Input $V_{REF} = 5V$	Digital Output Code (Hex)
FSR - 1 LSB	+4.999847 V	0x7FFF ¹
Midscale + 1 LSB	+152.6 μ V	0x0001
Midscale	0 V	0x0000
Midscale - 1 LSB	-152.6 μ V	0xFFFF
-FSR + 1 LSB	-4.999847 V	0x8001
-FSR	-5 V	0x8000 ²

¹ This is also the code for an overranged analog input ($V_{IN+} - V_{IN-}$ above $V_{REF} - V_{GND}$).
² This is also the code for an underranged analog input ($V_{IN+} - V_{IN-}$ below V_{GND}).



- 1 SEE REFERENCE SECTION FOR REFERENCE SELECTION.
- 2 C_{REF} IS USUALLY A 10 μ F CERAMIC CAPACITOR (X5R).
- 3 SEE TABLE 8 FOR ADDITIONAL RECOMMENDED AMPLIFIERS.
- 4 OPTIONAL FILTER. SEE ANALOG INPUT SECTION.
- 5 SEE THE DIGITAL INTERFACE SECTION FOR MOST CONVENIENT INTERFACE MODE.

Figure 26. Typical Application Diagram with Multiple Supplies

ANALOG INPUTS

Figure 27 shows an equivalent circuit of the input structure of the AD7693.

The two diodes, D1 and D2, provide ESD protection for the analog inputs, IN+ and IN-. Care must be taken to ensure that the analog input signal does not exceed the supply rails by more than 0.3 V because this causes the diodes to become forward biased and start conducting current. These diodes can handle a forward-biased current of 130 mA maximum. For instance, these conditions could eventually occur when the input buffer's (U1) supplies are different from VDD. In such a case, for example, an input buffer with a short-circuit, the current limitation can be used to protect the part.

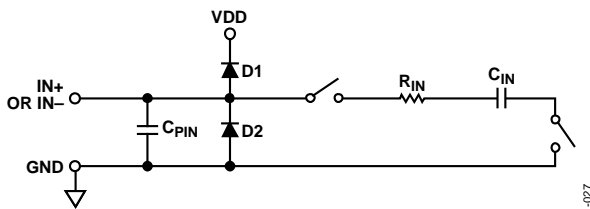


Figure 27. Equivalent Analog Input Circuit

The analog input structure allows the sampling of the true differential signal between IN+ and IN-. By using these differential inputs, signals common to both inputs are rejected.

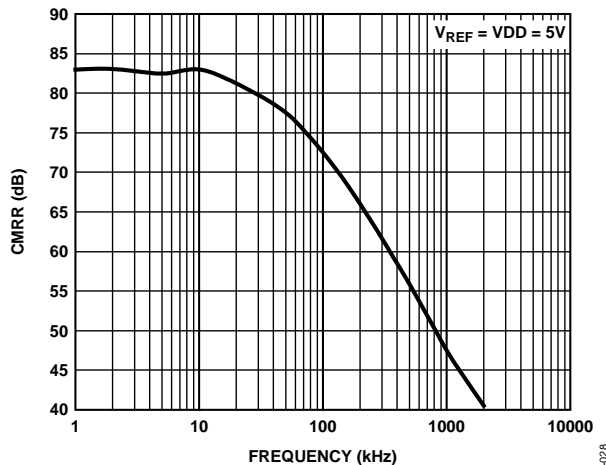


Figure 28. Analog Input CMRR vs. Frequency

During the acquisition phase, the impedance of the analog inputs (IN+ and IN-) can be modeled as a parallel combination of the capacitor, C_{PIN} , and the network formed by the series connection of R_{IN} and C_{IN} . C_{PIN} is primarily the pin capacitance. R_{IN} is typically 600 Ω and is a lumped component made up of serial resistors and the on resistance of the switches. C_{IN} is typically 30 pF and is mainly the ADC sampling capacitor.

During the conversion phase, where the switches are opened, the input impedance is limited to C_{PIN} . R_{IN} and C_{IN} make a 1-pole, low-pass filter that reduces undesirable aliasing effects and limits the noise.

When the source impedance of the driving circuit is low, the AD7693 can be driven directly. Large source impedances significantly affect the ac performance, especially total harmonic distortion (THD). The dc performances are less sensitive to the input impedance. The maximum source impedance depends on the amount of THD that can be tolerated. The THD degrades as a function of the source impedance and the maximum input frequency.

DRIVER AMPLIFIER CHOICE

Although the AD7693 is easy to drive, the driver amplifier must meet the following requirements:

- The noise generated by the driver amplifier needs to be kept as low as possible to preserve the SNR and transition noise performance of the AD7693. The noise coming from the driver is filtered by the AD7693 analog input circuit's 1-pole, low-pass filter made by R_{IN} and C_{IN} or by the external filter, if one is used. Because the typical noise of the AD7693 is 56 μV rms, the SNR degradation due to the amplifier is

$$SNR_{LOSS} = 20 \log \left(\frac{56}{\sqrt{56^2 + \frac{\pi}{2} f_{-3\text{dB}} (Ne_N)^2 + \frac{\pi}{2} f_{-3\text{dB}} (Ne_N)^2}} \right)$$

where:

$f_{-3\text{dB}}$ is the input bandwidth in megahertz of the AD7693 (9 MHz) or the cutoff frequency of the input filter, if one is used.

N is the noise gain of the amplifier (for example, 1 in buffer configuration).

e_N is the equivalent input noise voltage of the op amp, in $\text{nV}/\sqrt{\text{Hz}}$.

- For ac applications, the driver should have a THD performance commensurate with the AD7693.
- For multichannel multiplexed applications, the driver amplifier and the AD7693 analog input circuit must settle for a full-scale step onto the capacitor array at an 16-bit level (0.0015%, 15 ppm). In the amplifier's data sheet, settling at 0.1% to 0.01% is more commonly specified. This could differ significantly from the settling time at an 16-bit level and should be verified prior to driver selection.

Table 8. Recommended Driver Amplifiers

Amplifier	Typical Application
ADA4941-1	Very low noise, low power single to differential
ADA4841-x	Very low noise, small, and low power
AD8655	5 V single supply, low noise
AD8021	Very low noise and high frequency
AD8022	Low noise and high frequency
OP184	Low power, low noise, and low frequency
AD8605, AD8615	5 V single supply, low power

SINGLE-TO-DIFFERENTIAL DRIVER

For applications using a single-ended analog signal, either bipolar or unipolar, the [ADA4941-1](#) single-ended-to-differential driver allows for a differential input into the part. The schematic is shown in Figure 29.

R1 and R2 set the attenuation ratio between the input range and the ADC range (V_{REF}). R1, R2, and C_F will be chosen depending on the desired input resistance, signal bandwidth, antialiasing and noise contribution. For example, for the ± 10 V range with a 4 k Ω impedance, R2 = 1 k Ω and R1 = 4 k Ω .

R3 and R4 set the common mode on the IN $-$ input, and R5 and R6 set the common mode on the IN $+$ input of the ADC. The common mode should be set close to $V_{REF}/2$; however, if single supply is desired, it can be set slightly above $V_{REF}/2$ to provide some headroom for the [ADA4941-1](#) output stage. For example, for the ± 10 V range with a single supply, R3 = 8.45 k Ω , R4 = 11.8 k Ω , R5 = 10.5 k Ω , and R6 = 9.76 k Ω .

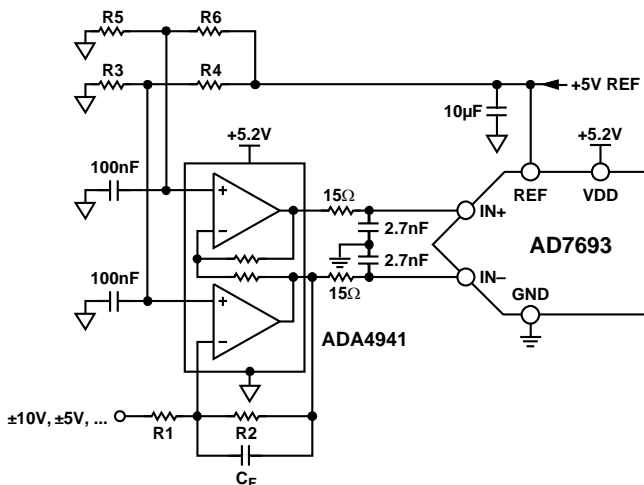


Figure 29. Single-Ended-to-Differential Driver Circuit

VOLTAGE REFERENCE INPUT

The AD7693 voltage reference input, REF, has a dynamic input impedance and should therefore be driven by a low impedance source with efficient decoupling between the REF and GND pins, as explained in the Layout section.

When REF is driven by a very low impedance source, for example, a reference buffer using the [AD8031](#) or the [AD8605](#), a 10 μ F (X5R, 0805 size) ceramic chip capacitor is appropriate for optimum performance.

If an unbuffered reference voltage is used, the decoupling value depends on the reference used. For instance, a 22 μ F (X5R, 1206 size) ceramic chip capacitor is appropriate for optimum performance using low temperature drift [ADR43x](#) and [ADR44x](#) references.

If desired, smaller reference decoupling capacitor values down to 2.2 μ F can be used with a minimal impact on performance, especially DNL.

Regardless, there is no need for an additional lower value ceramic decoupling capacitor (for example, 100 nF) between the REF and GND pins.

POWER SUPPLY

The AD7693 uses two power supply pins: a core supply, VDD, and a digital input/output interface supply, VIO. VIO allows direct interface with any logic between 1.8 V and V_{DD} . To reduce the supplies needed, the VIO and VDD pins can be tied together. The AD7693 is independent of power supply sequencing between VIO and VDD. Additionally, it is very insensitive to power supply variations over a wide frequency range, as shown in Figure 30.

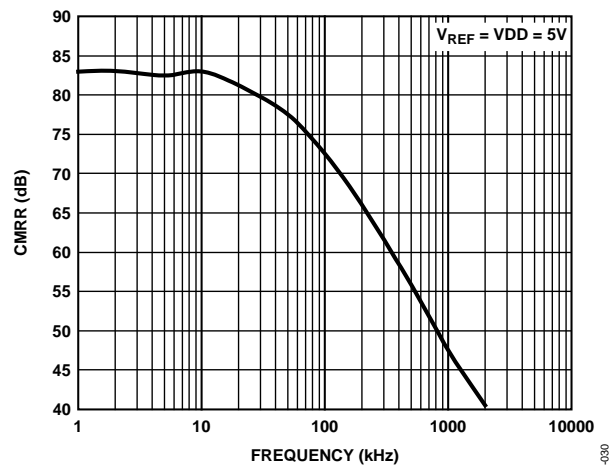


Figure 30. PSRR vs. Frequency

The AD7693 powers down automatically at the end of each conversion phase and, therefore, the power scales linearly with the sampling rate. This makes the part ideal for low sampling rate (even a few hertz) and low battery-powered applications.

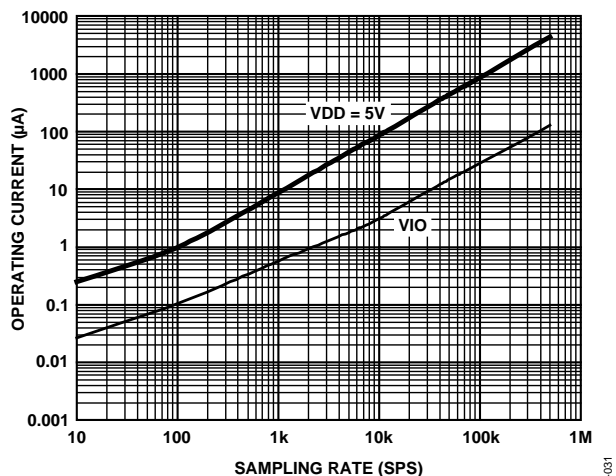
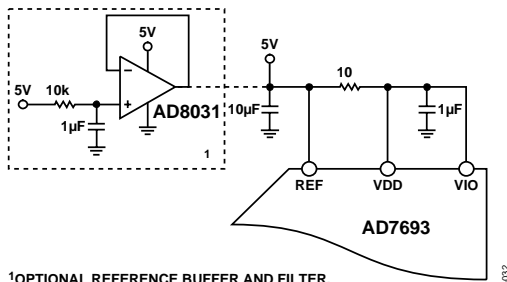


Figure 31. Operating Currents vs. Sample Rate

SUPPLYING THE ADC FROM THE REFERENCE

For simplified applications, the AD7693, with its low operating current, can be supplied directly using the reference circuit shown in Figure 32. The reference line can be driven by

- The system power supply directly.
- A reference voltage with enough current output capability, such as the [ADR43x](#).
- A reference buffer, such as the [AD8031](#), which can also filter the system power supply, as shown in Figure 32.



¹OPTIONAL REFERENCE BUFFER AND FILTER.

Figure 32. Example of Application Circuit

DIGITAL INTERFACE

Though the AD7693 has a reduced number of pins, it offers flexibility in its serial interface modes.

When in \overline{CS} mode, the AD7693 is compatible with SPI, QSPI, digital hosts, and DSPs, for example, Blackfin® ADSP-BF53x or

ADSP-219x. In this mode, the AD7693 can use either a 3-wire or 4-wire interface. A 3-wire interface using the CNV, SCK, and SDO signals minimizes wiring connections useful, for instance, in isolated applications. A 4-wire interface using the SDI, CNV, SCK, and SDO signals allows CNV, which initiates the conversions, to be independent of the readback timing (SDI). This is useful in low jitter sampling or simultaneous sampling applications.

When in chain mode, the AD7693 provides a daisy-chain feature using the SDI input for cascading multiple ADCs on a single data line similar to a shift register.

The mode in which the part operates depends on the SDI level when the CNV rising edge occurs. The \overline{CS} mode is selected if SDI is high, and the chain mode is selected if SDI is low. The SDI hold time is such that when SDI and CNV are connected together, the chain mode is selected.

In either mode, the AD7693 offers the option of forcing a start bit in front of the data bits. This start bit can be used as a busy signal indicator to interrupt the digital host and trigger the data reading. Otherwise, without a busy indicator, the user must timeout the maximum conversion time prior to readback.

The busy indicator feature is enabled

- In the \overline{CS} mode if CNV or SDI is low when the ADC conversion ends (see Figure 36 and Figure 40).
- In the chain mode if SCK is high during the CNV rising edge (see Figure 44).

$\overline{\text{CS}}$ MODE 3-WIRE, NO BUSY INDICATOR

This mode is usually used when a single AD7693 is connected to an SPI-compatible digital host. The connection diagram is shown in Figure 33, and the corresponding timing is given in Figure 34.

With SDI tied to VIO, a rising edge on CNV initiates a conversion, selects the $\overline{\text{CS}}$ mode, and forces SDO to high impedance. Once a conversion is initiated, it continues until completion irrespective of the state of CNV. This could be useful, for instance, to bring CNV low to select other SPI devices, such as analog multiplexers; however, CNV must be returned high before the minimum conversion time elapses and then held high for the maximum possible conversion time to avoid the generation of the busy signal indicator. When the conversion is complete, the AD7693 enters the acquisition phase and powers down. When CNV goes low, the MSB is output onto SDO. The remaining data bits are clocked by

subsequent SCK falling edges. The data is valid on both SCK edges. Although the rising edge can be used to capture the data, a digital host using the SCK falling edge will allow a faster reading rate, provided it has an acceptable hold time. After the 16th SCK falling edge, or when CNV goes high, whichever is earlier, SDO returns to high impedance.

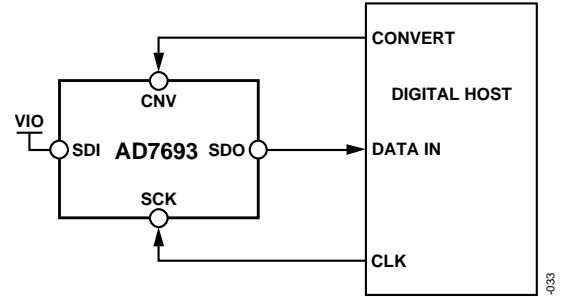


Figure 33. 3-Wire $\overline{\text{CS}}$ Mode Without Busy Indicator Connection Diagram (SDI High)

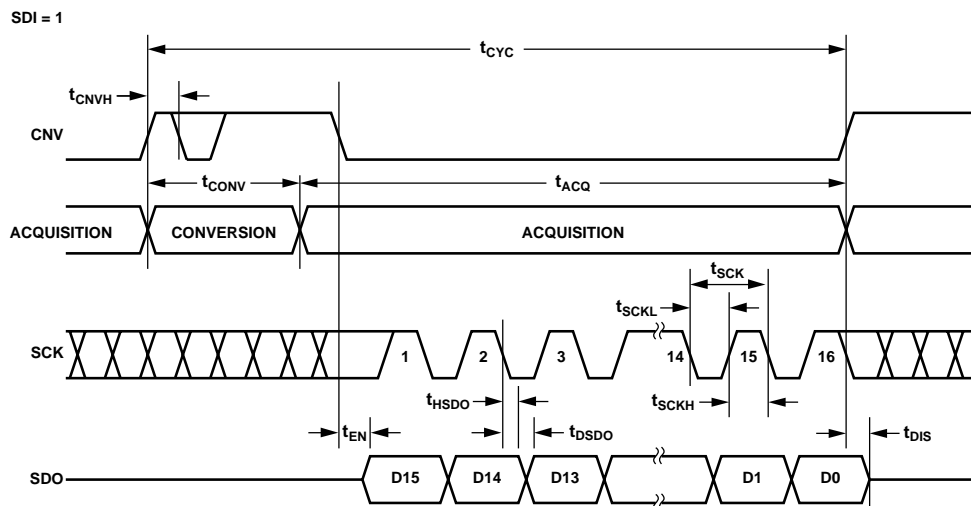


Figure 34. 3-Wire $\overline{\text{CS}}$ Mode Without Busy Indicator Serial Interface Timing (SDI High)

$\overline{\text{CS}}$ MODE 3-WIRE WITH BUSY INDICATOR

This mode is usually used when a single AD7693 is connected to an SPI-compatible digital host having an interrupt input.

The connection diagram is shown in Figure 35, and the corresponding timing is given in Figure 36.

With SDI tied to VIO, a rising edge on CNV initiates a conversion, selects the $\overline{\text{CS}}$ mode, and forces SDO to high impedance. SDO is maintained in high impedance until the completion of the conversion irrespective of the state of CNV. Prior to the minimum conversion time, CNV can be used to select other SPI devices, such as analog multiplexers, but CNV must be returned low before the minimum conversion time elapses and then held low for the maximum possible conversion time to guarantee the generation of the busy signal indicator. When the conversion is complete, SDO goes from high impedance to low impedance. With a pull-up on the SDO line, this transition can be used as an interrupt signal to initiate the data reading controlled by the digital host. The AD7693 then enters the acquisition phase and powers down. The data bits are clocked out, MSB first, by subsequent SCK falling edges.

data is valid on both SCK edges. Although the rising edge can be used to capture the data, a digital host using the SCK falling edge will allow a faster reading rate, provided it has an acceptable hold time. After the optional 17th SCK falling edge, or when CNV goes high, whichever is earlier, SDO returns to high impedance.

If multiple AD7693s are selected at the same time, the SDO output pin handles this contention without damage or induced latch-up. Meanwhile, it is recommended to keep this contention as short as possible to limit extra power dissipation.

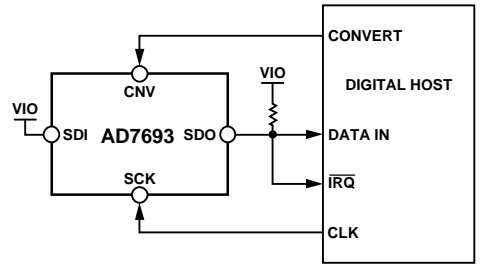


Figure 35. 3-Wire $\overline{\text{CS}}$ Mode with Busy Indicator Connection Diagram (SDI High)

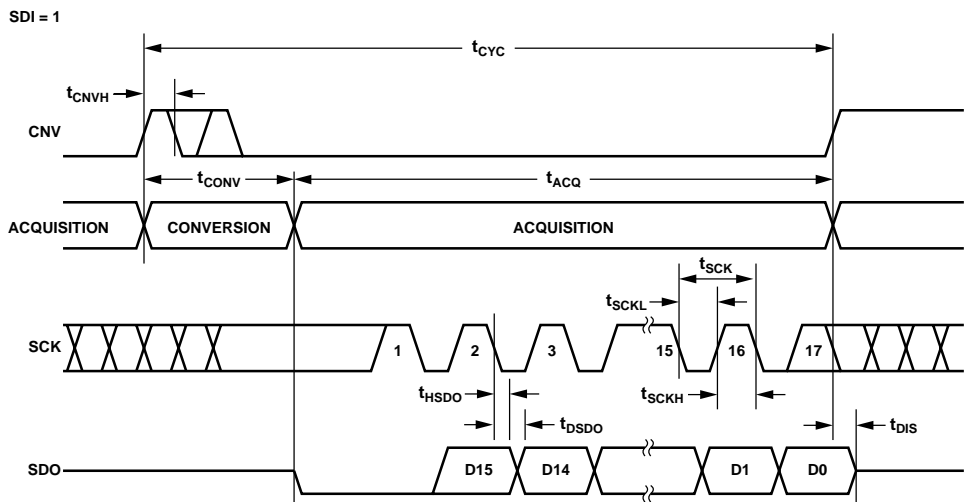


Figure 36. 3-Wire $\overline{\text{CS}}$ Mode with Busy Indicator Serial Interface Timing (SDI High)

\overline{CS} MODE 4-WIRE, NO BUSY INDICATOR

This mode is usually used when multiple AD7693s are connected to an SPI-compatible digital host.

A connection diagram example using two AD7693s is shown in Figure 37, and the corresponding timing is given in Figure 38.

With SDI high, a rising edge on CNV initiates a conversion, selects the \overline{CS} mode, and forces SDO to high impedance. In this mode, CNV must be held high during the conversion phase and the subsequent data readback. (If SDI and CNV are low, SDO is driven low.) Prior to the minimum conversion time, SDI can be used to select other SPI devices, such as analog multiplexers, but SDI must be returned high before the minimum conversion

time elapses and then held high for the maximum possible conversion time to avoid the generation of the busy signal indicator. When the conversion is complete, the AD7693 enters the acquisition phase and powers down. Each ADC result can be read by bringing its SDI input low, which consequently outputs the MSB onto SDO. The remaining data bits are clocked by subsequent SCK falling edges. The data is valid on both SCK edges. Although the rising edge can be used to capture the data, a digital host using the SCK falling edge will allow a faster reading rate, provided it has an acceptable hold time. After the 16th SCK falling edge, or when SDI goes high, whichever is earlier, SDO returns to high impedance and another AD7693 can be read.

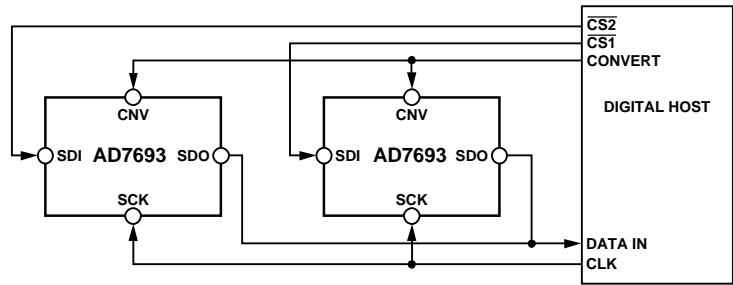


Figure 37. 4-Wire \overline{CS} Mode Without Busy Indicator Connection Diagram

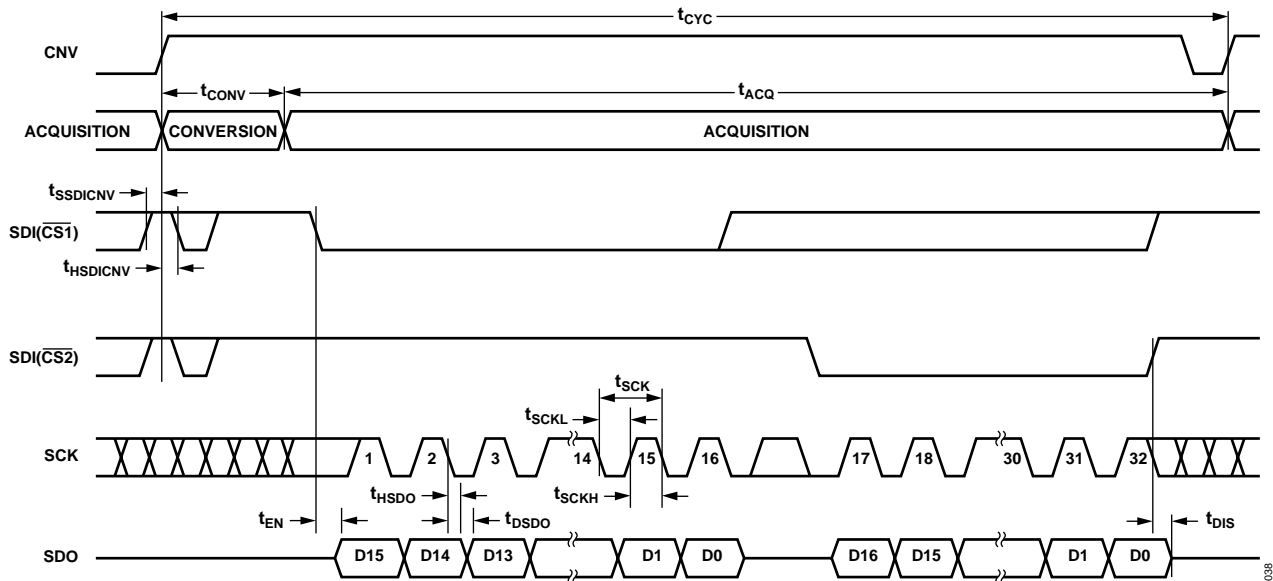


Figure 38. 4-Wire \overline{CS} Mode Without Busy Indicator Serial Interface Timing

\overline{CS} MODE 4-WIRE WITH BUSY INDICATOR

This mode is usually used when a single AD7693 is connected to an SPI-compatible digital host, which has an interrupt input, and it is desired to keep \overline{CNV} , which is used to sample the analog input, independent of the signal used to select the data reading. This requirement is particularly important in applications where low jitter on \overline{CNV} is desired.

The connection diagram is shown in Figure 39, and the corresponding timing is given in Figure 40.

With \overline{SDI} high, a rising edge on \overline{CNV} initiates a conversion, selects the \overline{CS} mode, and forces \overline{SDO} to high impedance. In this mode, \overline{CNV} must be held high during the conversion phase and the subsequent data readback. (If \overline{SDI} and \overline{CNV} are low, \overline{SDO} is driven low.) Prior to the minimum conversion time, \overline{SDI} can be used to select other SPI devices, such as analog multiplexers, but \overline{SDI} must be returned low before the minimum conversion time elapses and then held low for the maximum possible conversion time to guarantee the generation of the busy signal indicator. When the conversion is complete, \overline{SDO} goes from high impedance to low impedance. With a pull-up on the \overline{SDO}

line, this transition can be used as an interrupt signal to initiate the data readback controlled by the digital host. The AD7693 then enters the acquisition phase and powers down. The data bits are clocked out, MSB first, by subsequent \overline{SCK} falling edges. The data is valid on both \overline{SCK} edges. Although the rising edge can be used to capture the data, a digital host using the \overline{SCK} falling edge will allow a faster reading rate, provided it has an acceptable hold time. After the optional 17th \overline{SCK} falling edge, or \overline{SDI} going high, whichever is earlier, \overline{SDO} returns to high impedance.

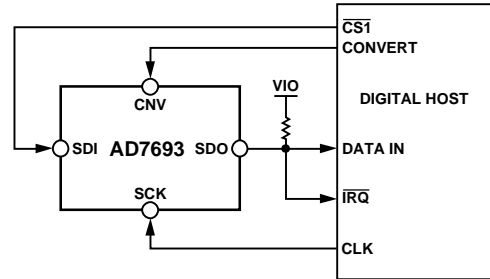


Figure 39. 4-Wire \overline{CS} Mode with Busy Indicator Connection Diagram

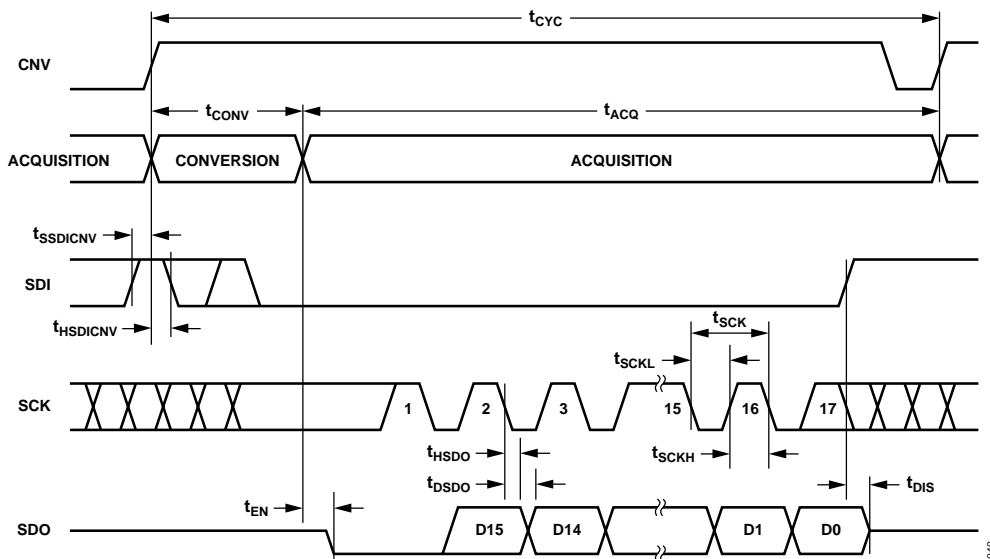


Figure 40. 4-Wire \overline{CS} Mode with Busy Indicator Serial Interface Timing

CHAIN MODE, NO BUSY INDICATOR

This mode can be used to daisy-chain multiple AD7693s on a 3-wire serial interface. This feature is useful for reducing component count and wiring connections, for example, in isolated multiconverter applications or for systems with a limited interfacing capacity. Data readback is analogous to clocking a shift register.

A connection diagram example using two AD7693s is shown in Figure 41, and the corresponding timing is given in Figure 42.

When SDI and CNV are low, SDO is driven low. With SCK low, a rising edge on CNV initiates a conversion, selects the chain mode, and disables the busy indicator. In this mode, CNV is held high during the conversion phase and the subsequent data

readback. When the conversion is complete, the MSB is output onto SDO and the AD7693 enters the acquisition phase and powers down. The remaining data bits stored in the internal shift register are clocked by subsequent SCK falling edges. For each ADC, SDI feeds the input of the internal shift register and is clocked by the SCK falling edge. Each ADC in the chain outputs its data MSB first, and $16 \times N$ clocks are required to read back the N ADCs. The data is valid on both SCK edges. Although the rising edge can be used to capture the data, a digital host using the SCK falling edge will allow a faster reading rate and consequently more AD7693s in the chain, provided the digital host has an acceptable hold time. The maximum conversion rate can be reduced due to the total readback time.

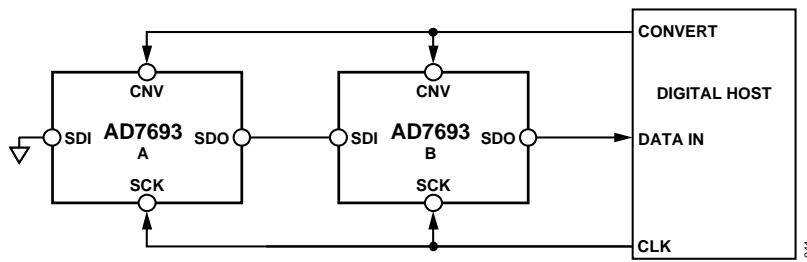


Figure 41. Chain Mode Without Busy Indicator Connection Diagram

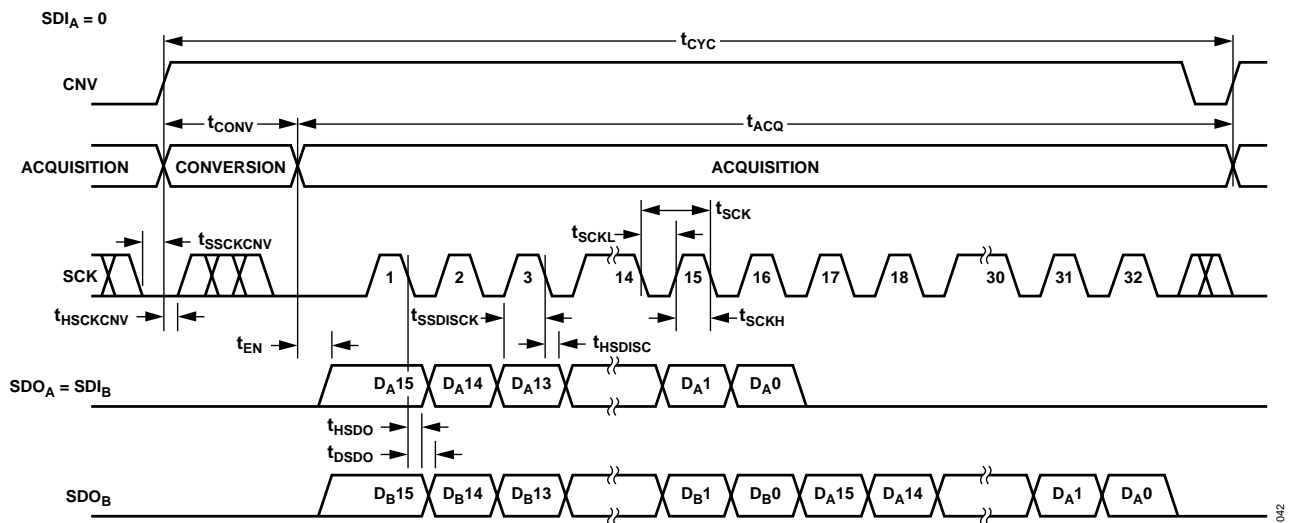


Figure 42. Chain Mode Without Busy Indicator Serial Interface Timing

CHAIN MODE WITH BUSY INDICATOR

This mode can also be used to daisy chain multiple AD7693s on a 3-wire serial interface while providing a BUSY indicator. This feature is useful for reducing component count and wiring connections, for example, in isolated multiconverter applications or for systems with a limited interfacing capacity. Data readback is analogous to clocking a shift register.

A connection diagram example using three AD7693s is shown in Figure 43, and the corresponding timing is given in Figure 44.

When SDI and CNV are low, SDO is driven low. With SCK high, a rising edge on CNV initiates a conversion, selects the chain mode, and enables the busy indicator feature. In this mode, CNV is held high during the conversion phase and the

subsequent data readback. When all ADCs in the chain have completed their conversions, the SDO pin of the ADC closest to the digital host (see the AD7693 ADC labeled C in Figure 43) is driven high. This transition on SDO can be used as a busy indicator to trigger the data readback controlled by the digital host. The AD7693 then enters the acquisition phase and powers down. The data bits stored in the internal shift register are clocked out, MSB first, by subsequent SCK falling edges. For each ADC, SDI feeds the input of the internal shift register and is clocked by the SCK falling edge. Each ADC in the chain outputs its data MSB first, and $16 \times N + 1$ clocks are required to readback the N ADCs. Although the rising edge can be used to capture the data, a digital host using the SCK falling edge allows a faster reading rate and consequently more AD7693s in the chain, provided the digital host has an acceptable hold time.

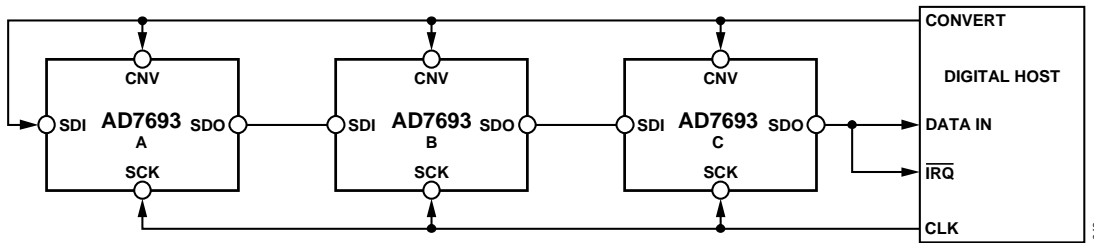


Figure 43. Chain Mode with Busy Indicator Connection Diagram

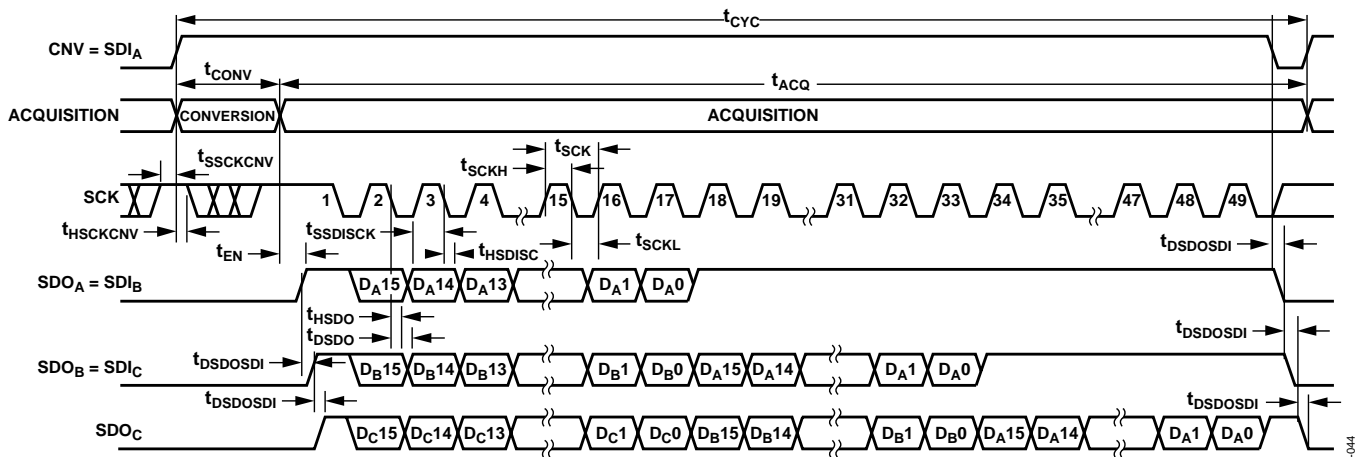


Figure 44. Chain Mode with Busy Indicator Serial Interface Timing

APPLICATION HINTS

LAYOUT

The printed circuit board that houses the AD7693 should be designed so that the analog and digital sections are separated and confined to certain areas of the board. The pinout of the AD7693, with all its analog signals on the left side and all its digital signals on the right side, eases this task.

Avoid running digital lines under the device because these couple noise onto the die unless a ground plane under the AD7693 is used as a shield. Fast switching signals, such as CNV or clocks, should not run near analog signal paths. Crossover of digital and analog signals should be avoided.

At least one ground plane should be used. It could be common or split between the digital and analog sections. In the latter case, the planes should be joined underneath the AD7693s.

The AD7693 voltage reference input REF has a dynamic input impedance and should be decoupled with minimal parasitic inductances. This is done by placing the reference decoupling ceramic capacitor close to, ideally right up against, the REF and GND pins and connecting them with wide, low impedance traces.

Finally, the power supplies VDD and VIO of the AD7693 should be decoupled with ceramic capacitors, typically 100 nF, placed close to the AD7693 and connected using short and wide traces to provide low impedance paths and reduce the effect of glitches on the power supply lines.

An example of a layout following these rules is shown in Figure 45 and Figure 46.

EVALUATING THE AD7693'S PERFORMANCE

Other recommended layouts for the AD7693 are outlined in the documentation of the evaluation board for the AD7693 ([EVAL-AD7693-CB](#)). The evaluation board package includes a fully assembled and tested evaluation board, documentation, and software for controlling the board from a PC via the [EVAL-CONTROL BRD3](#).

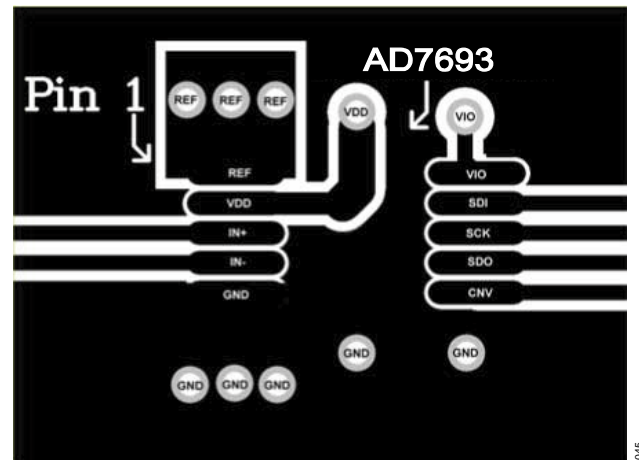


Figure 45. Example Layout of the AD7693 (Top Layer)

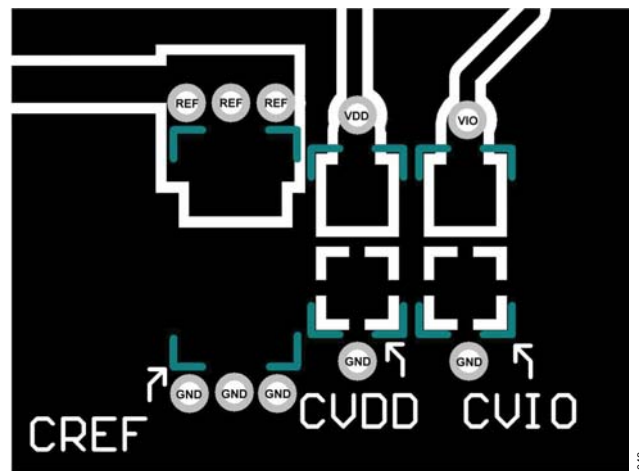
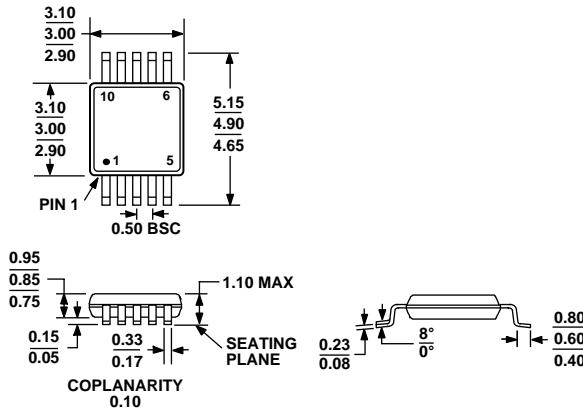


Figure 46. Example Layout of the AD7693 (Bottom Layer)

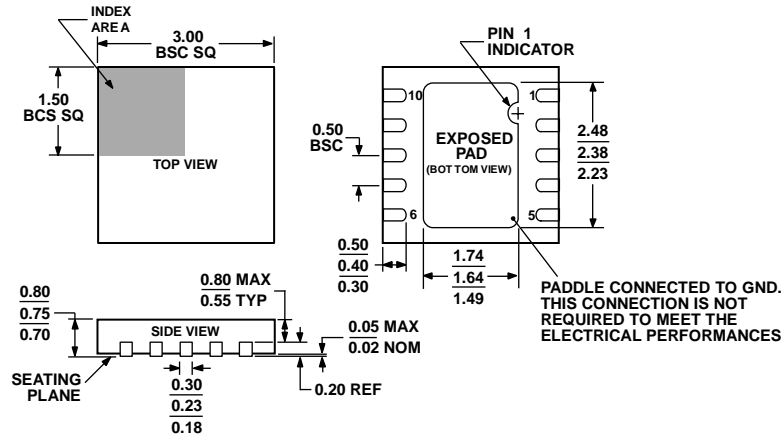
OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-187-BA

Figure 47.10-Lead Mini Small Outline Package [MSOP] (RM-10)

Dimensions shown in millimeters



QFN Package in development. Contact sales for samples and availability.

Figure 48. 10-Lead Lead Frame Chip Scale Package [QFN (LFCSP_WD)]
3 mm x 3 mm Body, Very Very Thin, Dual Lead (CP-10-9)

Dimensions shown in millimeters

ORDERING GUIDE

Model	Temperature Range	Ordering Quantity	Package Description	Package Option	Branding
EVAL-AD7693CB ¹			Evaluation Board		
EVAL-CONTROL BRD2 ²			Controller Board		
EVAL-CONTROL BRD3 ²			Controller Board		

¹ This board can be used as a standalone evaluation board or in conjunction with the EVAL-CONTROL BRDx for evaluation/demonstration purposes.

² These boards allow a PC to control and communicate with all Analog Devices evaluation boards ending in the CB designators.